Code: AC03 / AT03 Subject: BASIC ELECTRONICS & DIGITAL CIRC

AMIETE -CS/IT (OLD SCHEME)

Time: 3 Hours

DECEMBER 2011

Max. Marks: 100

DECLINIDEN 20

NOTE: There are 9 Questions in all.

- Please write your Roll No. at the space provided on each page immediately after receiving the Question Paper.
- Question 1 is compulsory and carries 20 marks. Answer to Q.1 must be written in the space provided for it in the answer book supplied and nowhere else.
- The answer sheet for the Q.1 will be collected by the invigilator after 45 Minutes of the commencement of the examination.
- Out of the remaining EIGHT Questions answer any FIVE Questions. Each question carries 16 marks.
- Any required data not explicitly given, may be suitably assumed and stated.

Q.1 Choose the correct or the best alternative in the following:

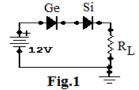
 (2×10)

- a. Which of the following is trivalent?
 - (A) Arsenic

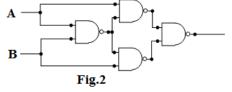
(B) Aluminum

(C) Phosphorus

- (**D**) Bismuth
- b. The value of load resistor in this circuit (Fig.1) is if current through the diode is 2mA
 - (A) 5K
 - **(B)** 5.5K
 - (C) 5.5Ω
 - **(D)** 4.5K



- c. Identify the output of the following circuit shown in Fig.2
 - (A) AND
 - (B) XOR
 - (C) XNOR
 - (D) NOR



- d. When simplified the result of expression $y = (\overline{A} + B)(A + B)$ is ____
 - (A) \overline{B}

(B) B

(**C**) A

- **(D)** AB
- e. A Zener diode has dc power dissipation rating of 50 mW and Zener voltage rating of 7.5 V The value of I_{ZM} is
 - (**A**) 76.76mA

(B) 66.67mA

(**C**) 76.68mA

(D) 67.86mA

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- f. In ECL logic family the logic swing with 5 V power supply is ___
 - (A) less than 2V

(B) 3.6V

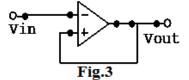
(C) 5V

- **(D)** 4V
- g. For a transistor $\beta = 40$, I $_{\rm B} = 25 \mu$ A, the value of I_E will be
 - (**A**) 1mA

(B) 1.025mA

(C) 0.975mA

- **(D)** $1.25\mu A$
- h. The opamp circuit shown in Fig.3 is
 - (A) Inverting Amplifier
 - (B) Voltage Follower
 - (C) Summer
 - **(D)** Active half wave



- i. How many 16K X 4 RAMS are required to achieve a memory with a capacity of 64K and word length of 8 bits?
 - **(A)** 4

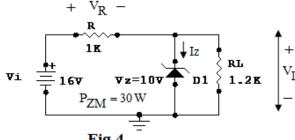
(B) 8

(C) 6

- **(D)** 16
- MOS circuits as compared to bipolar circuits take____
 - (A) same chip area
- **(B)** less chip area
- (C) more chip area
- (**D**) none

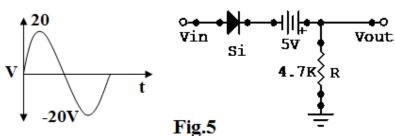
Answer any FIVE Questions out of EIGHT Questions. Each question carries 16 marks.

- **Q.2** a. Draw a neat schematic representation of p-n junction and explain what happens when junction is (i) forward biased (ii) reverse biased. Draw the practical VIcharacteristics of pn-junction diode and discuss the effect of temperature on current flowing through the diode?
 - b. With neat circuit diagram and input-output waveforms explain FET works as a switch?
 - c. (i) Find the values of V_L,V_R,I_Z and P_Z in the Zener network shown below in Fig.4 **(2)**

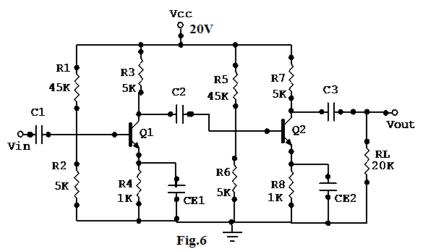


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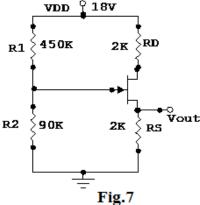
(ii) Sketch correct output waveform for the following circuit:



Q.3 Compute the overall voltage gain for the two stage-RC coupled amplifier shown in the Fig.6. Assume $V_{BE}=0.7V$ and β_1 (of Q1) = β_2 (of Q2) =100 (Hint:-Use r_{ρ} model) **(8)**



- b. Draw a neat circuit and prove that current gain in Darlington amplifier is β^2 (4)
- c. Given the following hybrid- π parameters for the transistor at I_C=10mA, $V_t = 0.026V$, $V_{CE}=10V$ and room temperature $h_{fe}=100$, $h_{ie}=500\Omega$, |Ai|=10at 10MHz, C_C =3pF. Find the values of (i) $r_{b'e}$ (ii) $r_{bb'}$ (iii) f_T and (iv) f_β (4)
- a. Determine I_D and V_{DS} if $V_P = -4V$ and $I_{DSS} = 10$ mA for the following circuit **Q.4** shown in Fig.7: **(6)**



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- b. A voltage 200 cos100t is applied to a half wave rectifier circuit having load resistance of $5K\Omega$. Rectifier may be represented as an ideal diode in series with resistance of $1K\Omega$. Find (i) Average value of current through the load and voltage across the load (ii) RMS current (iii) Rectifier efficiency (iv) PIV
- c. Design LC filter for full wave rectifier to provide output of 25 V with load current of 100mA and its ripple limited to 3%.
- Q.5 a. With neat circuit and input/output waveforms indicate how operational amplifier works as inverting and non-inverting amplifier derive expression for gain in each case.
 - b. Draw the circuit of Wien bridge oscillator and derive the expression for frequency of oscillations. List advantages and disadvantages of this circuit. (8)
- Q.6 a. Prove using Boolean laws that If $\overline{AB} + \overline{CD} = 0$ then expression $AB + \overline{C}(\overline{A} + \overline{D}) = AB + BD + \overline{BD} + \overline{ACD}$ (4)
 - b. Simplify using K-map and realize the result using only NOR gates. $f(A,B,C,D) = \prod (0,1,2,3,7,8,9,10,11) + d(6,14,15)$ (6)
 - c. Design 4:1 multiplexer using NAND gates only (6)
- Q.7 a. Explain basic TTL circuit and compare it with DTL in brief (6)
 - b. List any four characteristics ECL logic family. (4)
 - c. Sketch the circuit and characteristics of CMOS inverter and verify truth table for NOT operation. (6)
- Q.8 a. Sketch the circuit for SR flip-flops using NAND gates. Draw the truth table and obtain characteristic equation for the SR flip-flop .How to convert it into T flip-flop?
 (8)
 - b. Show how a modulo-4 counter designed with two flip-flops can generate a repetitive sequence of binary word 1101 with minimum number of memory elements? (8)
- Q.9 a. Discuss any six applications of ROM. (6)
 - b. What is latency time in CCD memory? Explain CCD memory organization in brief. (4)
 - c. What is Random Access Memory? How are they classified? List its advantage &.disadvantage with respect to ROM. (3)
 - d. How PLAs are different from ROM? Explain (3)